

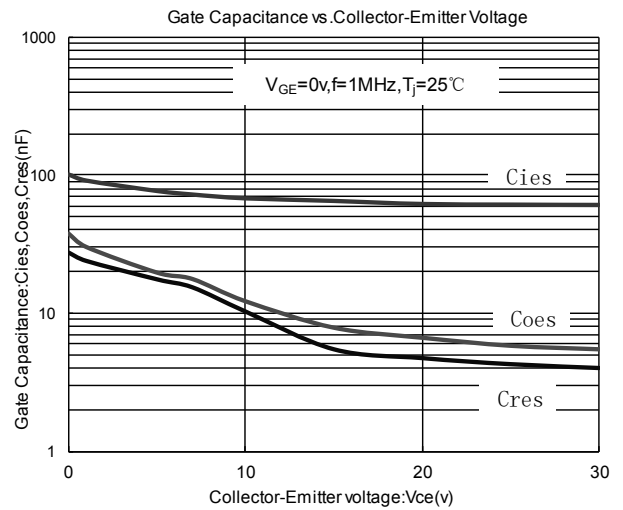
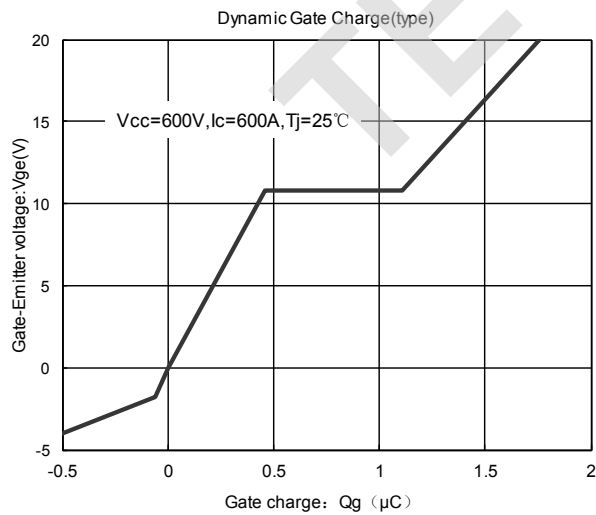
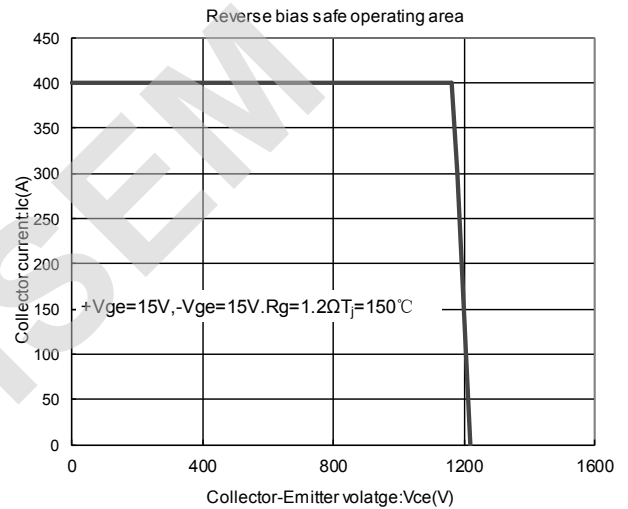
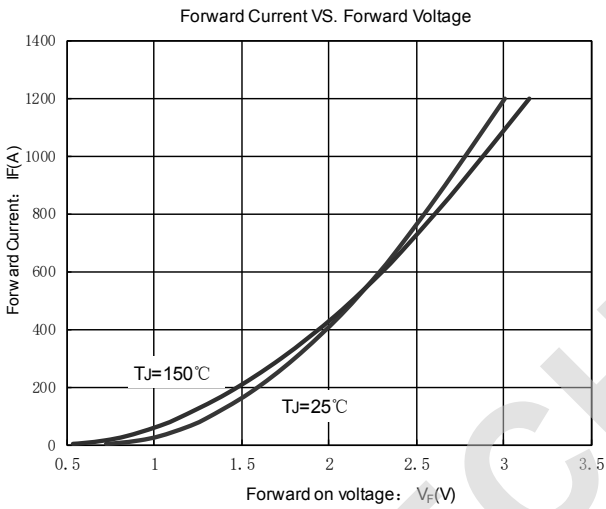
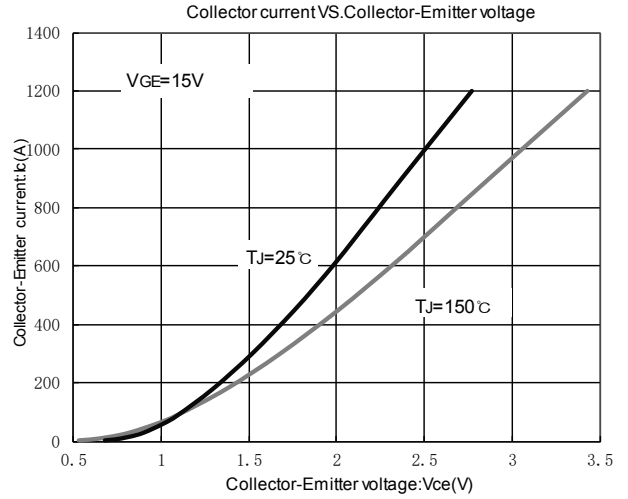
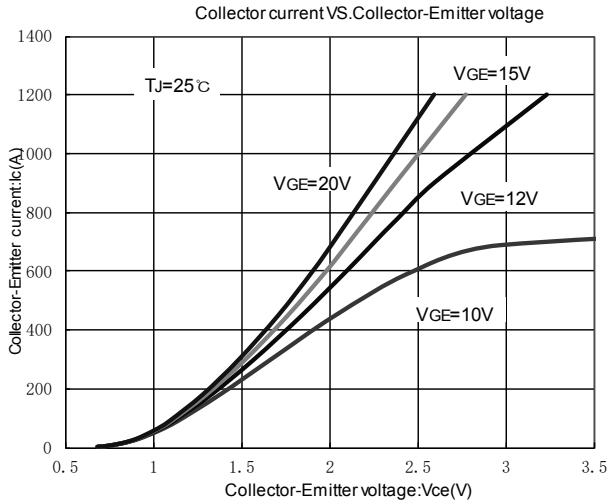
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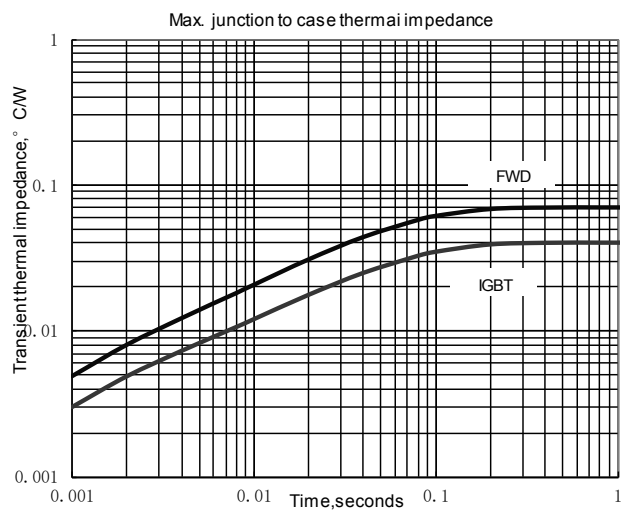
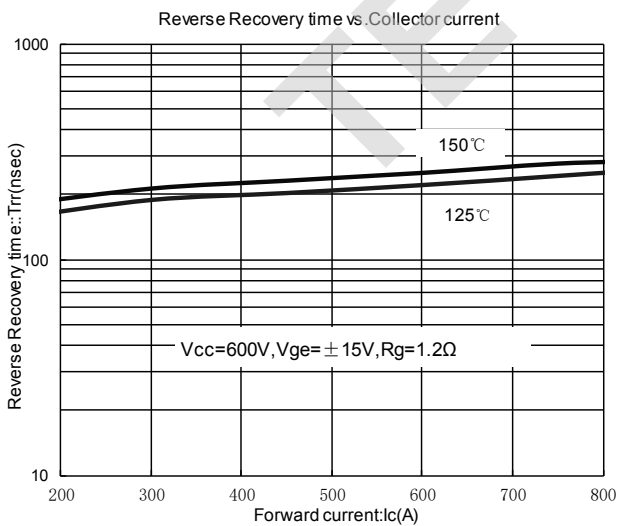
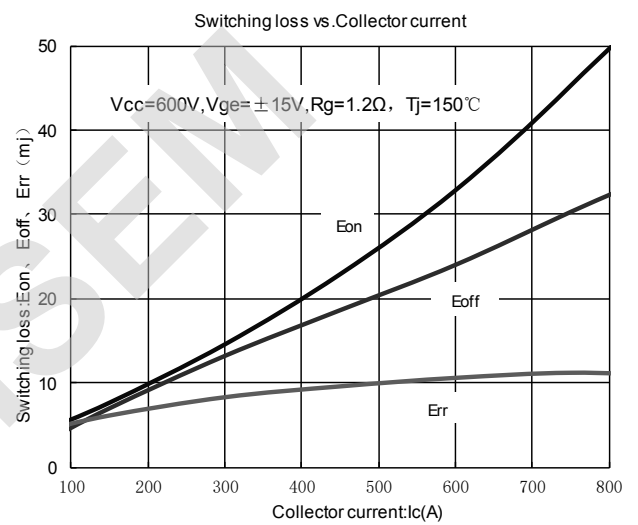
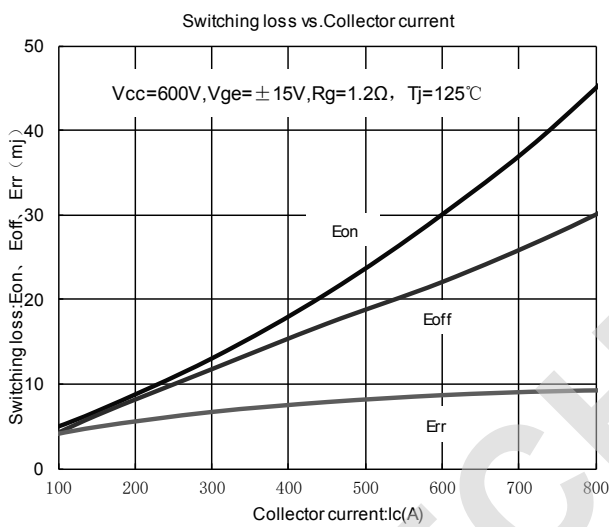
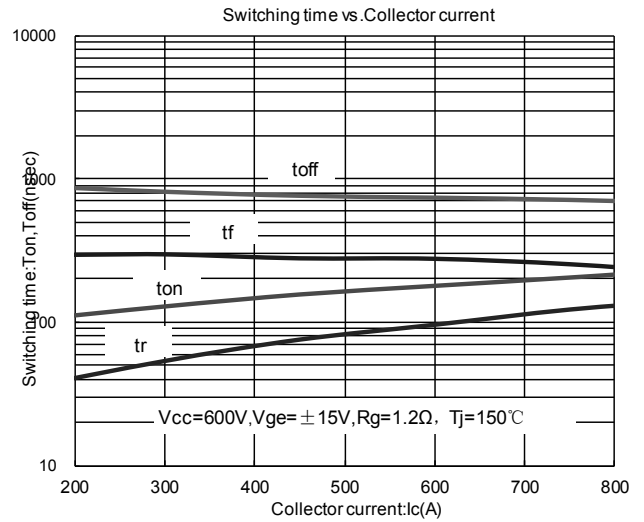
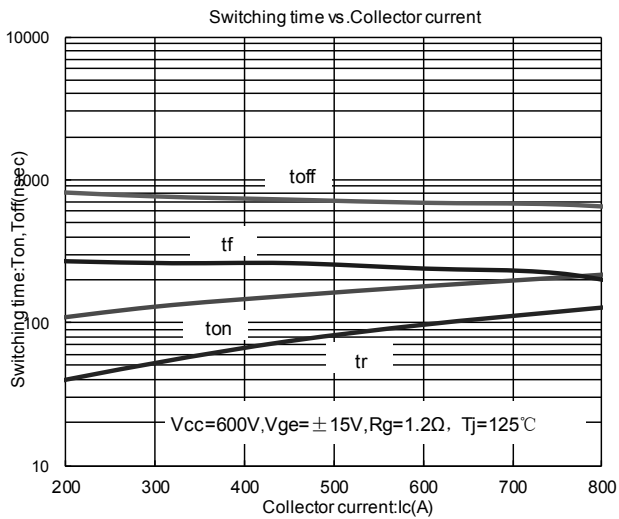
- Low V_{CEsat}
- Standard Housing

Typical Applications:

- Motor Drive
- Servo Drive
- Uninterruptible Power Supply System
- Wind Turbines
- High Power Converters

SYMBOL	CHARACTERISTIC	TEST CONDITIONS	VALUE			UNIT
			Min	Type	Max	
V_{CES}	Collector-Emitter voltage	$T_j=25^{\circ}C$			1250	V
V_{GES}	Gate-Emitter voltage	$T_j=25^{\circ}C$			± 30	V
I_C	Collector current	Continuous@ $T_C=100^{\circ}C$			600	A
I_{CP}		$T_P=1ms$			1200	A
P_C	Collector power dissipation	$T_j=150^{\circ}C$, 1 device			3750	W
T_j	Junction temperature	/			175	$^{\circ}C$
T_{stg}	Storage temperature	/	-40		125	$^{\circ}C$
V_{iso}	Isolation between terminal and copper base	$T_j=25^{\circ}C$, AC: 1minute	3000			V
Screw torque	Mounting(M6)	/	3.0	4.5	6.0	N·m
	Terminals(M6)	/	2.5	4.0	5.0	N·m
I_{CES}	Zero gate voltage collector current	$T_j=25^{\circ}C$, $V_{CE}=1200V$, $V_{GE}=0V$			1.5	mA
I_{GES}	Gate-Emitter leakage current	$T_j=25^{\circ}C$, $V_{CE}=0V$, $V_{GE}=\pm 20V$			± 0.5	μA
$V_{GE(th)}$	Gate-Emitter threshold voltage	$T_j=25^{\circ}C$, $V_{CE}=20V$, $I_C=150mA$	4.5		8.5	V
$V_{CE(sat)}$	Collector-Emitter saturation voltage	$T_j=25^{\circ}C$, $V_{GE}=15V$, $I_C=600A$		1.96	2.16	V
		$T_j=125^{\circ}C$, $V_{GE}=15V$, $I_C=600A$		2.25		V
		$T_j=150^{\circ}C$, $V_{GE}=15V$, $I_C=600A$		2.33		V
C_{ies}	Input capacitance	$T_j=25^{\circ}C$, $V_{CE}=10V$, $V_{GE}=0V$, $f=1MHz$		66.6		nF
t_{on}	Turn-on time	$T_j=150^{\circ}C$, $V_{CC}=600V$, $I_C=600A$, $V_{GE}=\pm 15V$, $R_g=1.2\Omega$, Inductive load		180		ns
t_r				95		ns
t_{off}				730		ns
t_f				270		ns
tsc	Short circuit withstand time	$T_j=150^{\circ}C$, $V_{CC}=720V$, $V_{GE}=\pm 15V$, $R_g=1.2\Omega$	10			μs
V_F	Forward on voltage	$T_j=25^{\circ}C$, $I_F=600A$		2.28	2.48	V
		$T_j=125^{\circ}C$, $I_F=600A$		2.26		V
		$T_j=150^{\circ}C$, $I_F=600A$		2.30		V
t_{rr}	Reverse recovery time	$T_j=125^{\circ}C$, $I_F=600A$		220		ns
		$T_j=150^{\circ}C$, $I_F=600A$		250		ns
$R_{th(j-c)}$	Thermal resistance(1 device)	IGBT			0.04	$^{\circ}C/W$
		FWD			0.07	$^{\circ}C/W$
$R_{th(c-f)}$	Contact thermal resistance (1 device)	With thermal compound		0.050		$^{\circ}C/W$
W_t	Weight				345	g
Outline		465H3				





Outline & Circuit Diagram

